Modification of Graphite Surface by Intense Pulsed Ion-beam Irradiation

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Surface modification has been carried out of graphite targets irradiated by intense pulsed ion beam. The highly oriented pyrolytic graphite (HOPG) targets were irradiated by 70 – 120 J/cm² of pulsed ion beams. To evaluate temperature on the irradiated surface, the deposited energy was measured by using the thermistors attached on the back of the targets. The fast heating and fast quenching occurred on the target surface, which were enhanced at the higher energy density of beam irradiation. On the irradiated surfaces, sphere particles and whiskers were found by scanning electron microscope observations. By Raman spectroscopy, structural changes were confirmed on the irradiated surfaces and the intensity ratio of a peak at 1360 cm⁻¹ to that at 1580 cm⁻¹ was increased with increasing the ion beam energy density.

**Keywords**: pulsed ion beam, high-density ablation plasma, surface modification, Raman spectroscopy

1. Introduction

It is widely known that there are many allotropes of carbons, such as graphite, diamond and diamond-like-carbon (DLC). Their physical properties are strongly dependent on the ratio of sp² (graphite-like) and sp³ (diamond-like) bonds. The ratio varies with synthesizing conditions including the pressure and the temperature. Not only synthesis of the bulk samples, but also modification of the bulk surface of the carbon have been carried out by shock wave(1), pulsed laser irradiation(2)(3) and ion irradiation.

In the ion irradiation method, the irradiated ions can travel only a very short distance in the target due to strong interaction with material. This distance is called the range. For instance, the range is only ~13 μm for the proton with the energy of 1 MeV in a carbon target. Being dependent on the ion beam energy density deposited, the ion irradiation can be divided into two processes for modifying the graphite surface, i.e. ion implantation and ion-beam ablation. In the ion implantation, the ion flux of approximately 10⁻⁷–10⁻¹⁰ ions/(cm²·s) were applied on the graphite target, where the lattice damage was observed in the target(4). On the other hand, by applying an intense pulsed ion beam, it is easily possible to raise the temperature above a melting point of the target. The heated surface layer turns into a high-density ablation plasma(5). And then, the target surfaces can be heated and the pressure wave propagates in the target.

In our previous works, we have studied the kinetics of the aluminum targets by the pulsed ion-beam irradiation(5)(6). From these works, we have found experimentally and analytically that not only temperature but also pressure of the ablation plasma were enhanced at the higher energy density of the ion beam irradiation. Thus, it may be possible to control the pressure and the temperature in the targets, and we expect the surface modification of the target materials. The temperature or pressure effect of the target materials using the pulsed ion beam has recently attracted considerable attention in the field of surface modification. Preliminary data on the surface modification of graphite by the pulsed ion beam irradiation was reported by the present authors, but the temperature of the target was not studied.

In this paper, we attempted the surface modification of graphite targets by the pulsed ion beam irradiation. The highly oriented pyrolytic graphite (HOPG) targets were irradiated by the ion beams with energy density of 70 – 120 J/cm². To evaluate the surface temperature at the instance of the ion-beam irradiation, a thermal energy deposited into the target was measured by the thermistor. The carbon ablation plasma was observed by an ultra high-speed camera. The morphology of the irradiated surface was observed by a scanning electron microscopy (SEM). The structure of the irradiated targets was investigated by a Raman spectroscopy.

2. Experimental Setup

2.1 Ion Beam Diode

The ion-beam irradiation experiments were carried out in a pulsed power generator, "ETIGO-II"(7). Figure 1 illustrates the outline of the experimental setup using a magnetically insulated ion-beam diode (MID)(3). The diode consisted of the anode (inner electrode) and the cathode (outer electrode). The concave-shaped anode had a flashboard (polyethylene) on its surface. The cathode had slits to extract the ion beam. In addition, the cathode acted as a one-turned theta-pincho coil, where the current was supplied by an external power supply of a capacitor bank. The current in the cathode generated an insulating magnetic field in the gap between the cathode and the anode, by which the electrons emitted from the cathode were prevented from arriving at the anode. On the other hand, the ions (approximately 75% proton) were accelerated toward the cathode and focused toward the geometric focusing point (dreq = 160 mm) through a vane-structure cathode. The peak voltage of the diode was 1.1 MV. The pulse width was approximately 60 ns. The diode and the target chambers were evacuated to 2 × 10⁻⁴ Torr of pressure during the experiments.

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The ion-beam energy density was measured by a calorimeter at various distance between the anode and the target material ($d_{AT}$). Figure 2 shows the average energy density as a function of $d_{AT}$. The maximum average energy density of 120 J/cm$^2$ was obtained at $d_{AT} = 150$ mm, which is 10 mm closer than the geometric focal point due to a self-magnetic field. The energy density is decreased at $d_{AT} > 150$ mm.

2.2 Deposited Energy Measurement Figure 3 illustrates the schematic of the deposited energy measurement by using the thermistor. The HOPG (Advanced Ceramics Corporation, Grade ZYH) plates with thickness of 1 mm was used for the target. The physical properties of the HOPG were shown in Table 1. The temperature rise of the target ($\Delta T$) was measured by the thermistor (SYE-64: Technol Seven Co.). The thermistor was placed on the backside of the HOPG target. The target was located behind an aperture (8 mm$^2$). The deposited energy $Q$ (J) into the target is given by

$$Q = mc\Delta T$$

(1)

where $m$ (g) is the mass of the target and $C$ (J/K·g) the specific heat of the target (0.7 J/K·g for carbon). The deposited energy per unit area $H$ (J/cm$^2$) is given by

$$H = Q/S$$

(2)

where $S$ (cm$^2$) is the irradiated area. The time evolution of the ablation plasma was observed by a high-speed camera (NAC Inc., ULTRA-NAC). The photographs were taken with the exposure time of 30 ns and the inter-frame of 500 ns.

2.3 Surface Modification In the surface modification experiments, the HOPG targets were irradiated by the ion beams with energy density of 70–120 J/cm$^2$. One of the targets was set parallel to the cathode, and $d_{AT}$ was changed at 150 and 180 mm. The number of shots for each target was one. The morphology of the ablated surfaces was observed by a scanning electron microscope (JEOL, ISM-6700F). The Raman spectra were obtained using a Model Labram Infinity spectroScope (Jobin Yvon Co.), in a backscattering mode using an argon-ion laser with the wavelength of 514.5 nm at a power of 10 mW.

3. Experimental Results and Discussions

3.1 Evaluation of Temperature on the Target Surface Figure 4 shows typical high-speed photographs of the ablation plasma, where the HOPG target was irradiated by 70 J/cm$^2$ of the ion beam. The HOPG target was placed in the absence of the aperture on the target holder. The ion beam irradiates the target from the right-hand side. We observed the plasma light on the target surface for approximately 1 µs after the beam irradiation.

Figure 5 shows the time evolution of the deposited energy on the HOPG targets. Here, the HOPG targets were placed at $d_{AT} = 160$ and 180 mm, where the ion beams with 100–120 J/cm$^2$ of the energy density were irradiated on the targets, respectively. The time of zero in Fig. 5 corresponds to the start of the beam irradiation on the target. The maximum deposited energy ($Q$) of 0.8 and 0.6 J was obtained with each condition. Thus, the deposited energy per unit area ($H$) were estimated to be 1.6 and 1.3 J/cm$^2$, respectively. Since the ablated area on the target has been observed to be same as the target size, and the targets were
used always flat and thin plates, the heat diffusion in the targets can be considered to be one-dimensional. Assuming the heat diffusion from the ablation plasma being constant during the period \( \tau \) (sec), the heat flux \( F_0 \) (W/cm\(^2\)) is given by

\[
F_0 = \frac{H}{\tau} \quad \text{Eq. (3)}
\]

In Fig. 4, the strong light emission of the ablation plasma on the target surface was observed for approximately 1 \( \mu \)s, being correspond to \( \tau \). Assuming the target was deposited by the thermal energy for the duration of 1 \( \mu \)s, we obtained the heat flux \( F_0 \) of \( 1.6 \times 10^6 \) and \( 1.3 \times 10^6 \) W/cm\(^2\) for \( d_{av} \) = 160 and 180 mm samples, respectively.

In the one-dimensional heat diffusion in the direction perpendicular to the target surface, the surface temperature \( T \) (\(^\circ\)C) can be evaluated by following equations\(^{11)(12)}\):

\[
T(i) = \frac{2F_0}{K} \frac{\kappa}{\pi} \left( \sqrt{t} - \sqrt{i - \tau} \right) \quad \text{for } 0 < t < \tau \quad \text{Eq. (4)}
\]

\[
T(i) = \frac{2F_0}{K} \frac{\kappa}{\pi} \frac{1}{\sqrt{\pi}} \quad \text{for } t > \tau \quad \text{Eq. (5)}
\]

where \( K \) is the thermal conductivity (W/cm \( \cdot \)K) and \( \kappa \) the thermal diffusivity (cm\(^2\)/s).

Substituting the present conditions into eqs. (4) and (5), we obtained the time evolution of the surface temperature as shown in Fig. 6. We see the target surfaces were quickly heated by the ablation plasma, and then quenched. In the phase diagram of carbon, the phase change between solid and liquid phase exist at \(-5000^\circ\)C. Therefore, at \( d_{av} = 160 \) mm, it is expected that the surface of solid graphite changes to liquid phase graphite by the ablation plasma. The structural changes will be expected by these thermal effects.

### 3.2 Surface Modification of Graphite Targets by Ion Beam Irradiation

Figure 7 shows SEM images of the surface of (a) unirradiated, (b) irradiated HOPG targets and (c) the magnified image of the point P in Fig. 7(b). The irradiated sample was placed at \( d_{av} = 150 \) mm, where the ion beams with \(-120 \) J/cm\(^2\) of energy density were irradiated on the target. The observed area was the center of the irradiated region on the target surface. From Fig. 7(b) and (c), the irradiated sample has many sphere particles and whiskers. The diameter of these particles was approximately 0.5-1 \( \mu \)m. The surface morphology of other samples which was irradiated at \( d_{av} = 180 \) mm were similar to that of Fig. 7(b). Figure 8 shows the cross sectional view of the irradiated HOPG target. The cavity whiskers were clearly observed on the irradiated target surface.

The growth mechanism of the metallic whisker from solids was studied by many scientists. Furuta et al.\(^{(33)}\) studied the growth of Sn whiskers from a solid Al-Sn alloy. The whiskers were formed by growing a topmost grain in the strained alloy. Fisher\(^{(4)}\) and Hasiguti\(^{(15)}\) observed the growth of whiskers from solid Sn plated Zn samples. The growth rate was increased with increasing applied pressure by exerted in tightening the clamp. In the present experiment of the intense pulsed ion beam irradiation on the graphite target, carbon whiskers were observed to be present (Fig. 7(b)). Although, as far as the present authors know, no results have been reported on the growth of carbon whiskers from solid, it is likely that the growth of carbon whiskers will be enhanced by the hydraulic pressure. Hence, the presence of the carbon whiskers observed in Fig. 7(b) on the pulsed ion beam irradiation on the graphite samples may give us an evidence of the generation of hydraulic pressure, which had been numerically predicted by the previous studies.

The structure of the irradiated targets was investigated by the Raman spectroscopy. Figure 9 shows the typical Raman spectra of the irradiated targets. The HOPG targets were placed at \( d_{av} = 150 \) and 180 mm, where ion beams with \(-120 \) and \(-70 \) J/cm\(^2\) of
Fig. 7. Surfaces of (a) unirradiated, (b) irradiated HOPG targets observed by SEM. (c) is the magnified image of point P in Fig. 7(b).

Fig. 8. Cross sectional view of the irradiated HOPG target observed by SEM.

Energy density were irradiated on the targets, respectively. The observed area was the center of the irradiated region. In the unirradiated target, the sharp peak can be observed in the spectrum at ~1580 cm⁻¹, called G peak. The G peak corresponds to an in-plane vibration of graphite structure (E₂g), which indicates the presence of sp² bonds. In the irradiated target, the broad peak can be observed in the spectrum at ~1360 cm⁻¹, called D peak. The D peak, corresponds to the structural defects in graphite. The FWHM and the ratio of the peak intensity of those peaks give us the information about the microstructure of the carbon material. After the beam irradiation, the FWHM values of G and D peaks are broadened and that the intensities of D peak are enhanced. On the Raman spectra of the graphite, many scientists have studied the relation between the peak shift of the D or G peaks and disordering of the crystalstructure. In our experiments, however, no peak shift could be observed.

The intensity ratio of D peak to G peak (I_D/I_G) is very important because it indicates the degree of disordering. In the present experiment, the intensity ratio of I_D/I_G is clearly increased with increasing the ion-beam energy density. Thus, the degree of disordering is enhanced at the higher energy density.

The result of the SEM and Raman spectroscopy analysis, it is suggested that the pressure and temperature generated by the ablation plasma is influenced by the beam irradiated targets. The above consideration can be supported by the presence of the whiskers on the irradiated surface and the structural changes in HOPG target investigated by the Raman spectroscopy. It is possible to modify the surface structure at the higher energy density of beam irradiation.

4. Conclusions

The surface modification of the highly oriented pyrolytic graphite (HOPG) targets have been carried out by the pulsed ion-beam irradiation. To evaluate the irradiated surface temperature, the deposited energies with the ablation-plasma radiation on the HOPG targets were measured. The maximum deposited energy was obtained to be 0.8 J with 100 J/cm² of the ion-beam irradiation. The fast heating and fast quenching effects were observed on the target surface, and these effects can be enhanced at the higher energy density of beam irradiation.

In the SEM analysis, sphere particles and whiskers which approximately 0.5–1 μm in diameter were observed on the irradiated surface. These whiskers may be grown under the hydraulic pressure by the ablation-plasma radiation. In the Raman spectra, we see the intensity ratio of I_D/I_G was increased with increasing the ion-beam energy density. These results suggested us that the pressure and temperature effects provided by the ablation plasma were valid on the surface modification of the graphite targets by pulsed ion beam irradiation. We have found...
the ablation plasma produced by the intense pulsed ion-beam irradiation can be used for the surface modification of the target materials.

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References


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